## NSN 5961-01-342-9714

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-342-9714 **Inclosure Material:** Plastic **Overall Length:** 0.860 inches **Overall Height:** 0.640 inches **Overall Width:** 0.200 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-218ac **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 550.0 drain to source voltage and 550.0 drain to gate voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 6.00 amperes drain current and 30.00 amperes off-state current, peak **Power Rating Per Characteristic:** 150.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: